Tab

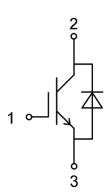


High voltage, reverse conducting IGBT with monolithic body diode

WGD30J135FRA2

Features

- Vces=1350V
- $I_{C}=30A@T_{C}=100^{\circ}C$
- Very low Vcesat
- High speed switching
- Low EMI
- Powerful monolithic body diode with low forward voltage designed for soft commutation
- Very tight parameter distribution
- High ruggedness, temperature stable behavior
- RoHS compliant, halogen free



Applications

- Inductive cooking
- Soft switching applications
- Inverterized microwave ovens







Package pin definition	1	2/Tab	3	
	Gate	Collector	Emitter	

Part	Package	Marking	Packing method	MPQ
WGD30J135FRA2	TO-247	30J135FRA2	Tube	30/Tube





1 Maximum Ratings

Table 1 Maximum rated Values(T_c=25℃ unless otherwise specified)

Parameter	Symbol	Condition	Values	Unit
Collector to Emitter Voltage	V _{CES}		1350	V
Gate to Emitter Voltage	V _{GES}		±20	V
Continuous Collector Current			60	А
Continuous Collector Current	I _C	T _C =100°C	30	А
Pulsed Collector Current ¹	I _{CM}		120	Α
Diode Continuous Forward Current	I _F		60	А
Diode Continuous Forward Current		T _C =100°C	30	А
Diode Maximum Forward Current ¹	I _{FM}		120	А
Maximum Dawar Dissination	P _{tot}		300	W
Maximum Power Dissipation		T _C =100℃	150	W
Operating Junction Temperature Range	TJ		-55~+175	℃
Storage Temperature Range	T _{STG}		-55~+150	$^{\circ}$
Thermal Resistance, Junction to case for IGBT	R _{th(J-C)}		0.50	K/W
Thermal Resistance, Junction to case for Diode	R _{th(J-C)}		0.79	K/W

Notes:

1. Pulse width limited by maximum junction temperature.





2 Electrical Characteristics, IGBT

Table 2 Characteristics Values(T_c=25℃ unless otherwise specified)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Collector to Emitter Breakdown Voltage	BVces	I _C =0.5mA, V _{GE} =0V	1350	-	-	V
	VCE(sat)	I _C =30A, V _{GE} =15V	-	1.65	2.15	V
Collector to Emitter Saturation Voltage		I _C =30A, V _{GE} =15V, T _J =150°C	-	2.1	-	V
Gate Threshold Voltage	V _{GE(th)}	Ic=250µA, V _{GE} =V _{CE}	4.8	5.8	6.8	V
Zero Gate Voltage Collector current	Ices	V _{CE} =600V, V _{GE} =0V	-	-	100	μΑ
Gate to Emitter Leakage Current	I _{GES}	V _{GE} =±20V, V _{CE} =0V	-	-	±200	nA
Internal Gate Resistor	R _{Gint}	f=1MHz, V _{AC} =25mV	-	1.2	-	Ω
Input Capacitance	C _{ies}		-	3276	-	pF
Output Capacitance	Coes	f=100kHz, V _{CE} =25V, V _{GE} =0V	-	48	-	pF
Reverse Transfer Capacitance	Cres		-	16	-	pF
Total Gate charge	Q _G		-	127	-	nc
Gate to Emiter charge	Q _{GE}	Vcc=600V, Ic=30A, VgE=15V	-	34	-	nc
Gate to Collector charge	Q _{GC}		-	44	-	nc
Turn-off Delay Time	t _{d(off)}	Vcc=600V, Ic=30A, VgE=0/15V,	-	138	-	ns
Falling Time	t _f	R _G =10Ω, T _J =25°C	-	204	-	ns
Turn-off Switching Loss Energy	E _{off}	Inductive load	-	1.70	-	mJ
Turn-off Delay Time	t _{d(off)}	V _{CC} =600V, I _C =30A, V _{GE} =0/15V,	-	158	-	ns
Falling Time	t _f	R _G =10Ω, T _J =150°C	-	272	-	ns
Turn-off Switching Loss Energy	E _{off}	Inductive load	-	2.23	-	mJ





3 Electrical Characteristics, Diode

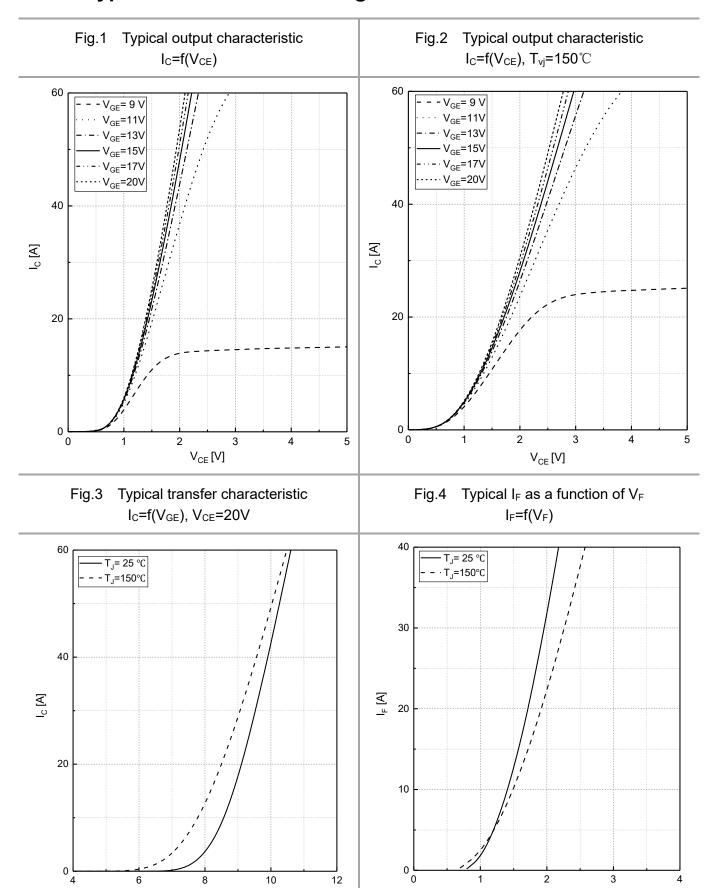
Table 3 Characteristics Values(T_c=25℃ unless otherwise specified)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Forward Voltage	VF	I⊧=30A, Tյ=25℃	-	2.00	2.5	V
		I _F =30A, T _J =150°C	-	2.3	-	V





4 Typical Characteristics diagrams



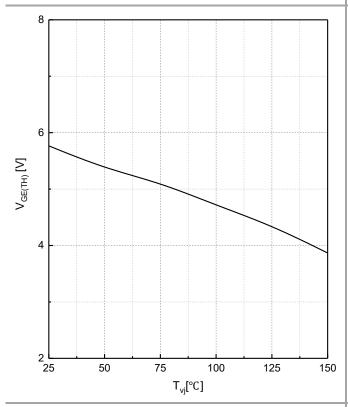
 $V_{GE}[V]$

 $V_F[V]$



Fig.5 Typical $V_{GE(th)}$ as a function of T_{vj} $V_{GE(th)} = f(T_{vj}), \ I_C = 250 \mu A$

Fig.6 Typical V_{CEsat} as a function of T_{vj} V_{CEsat} =f(T_{vj}), V_{GE} =15V



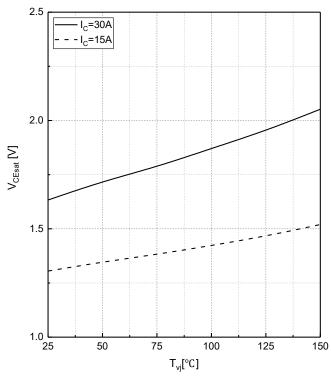
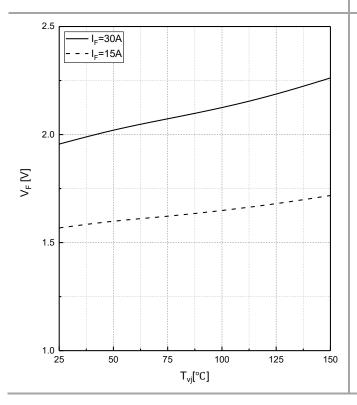


Fig.7 Typical V_F as a function of T_{vj} $V_F = f(T_{vj})$

Fig.8 Typical Turn-off switching loss energy as a function of $R_{\mbox{\scriptsize G}}$

 $E=f(R_G)$, $V_{CC}=600V$, $I_C=30A$, $V_{GE}=0/15V$, $T_J=150$ °C



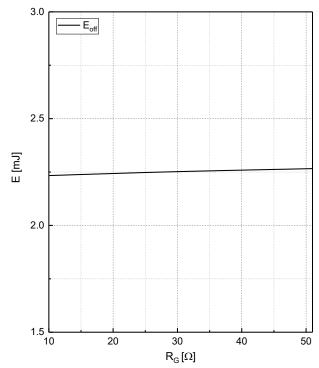
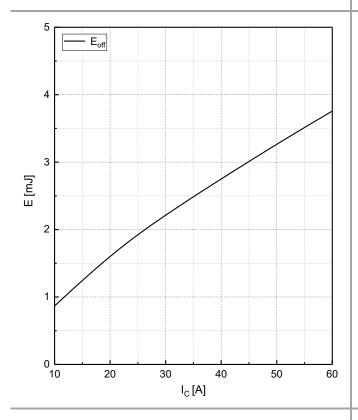




Fig.9 Typical Turn-off switching loss energy as a function of $I_{\mathbb{C}}$

 $E=f(I_C)$, $V_{CC}=600V$, $R_G=10\Omega$, $V_{GE}=0/15V$, $T_J=150^{\circ}C$

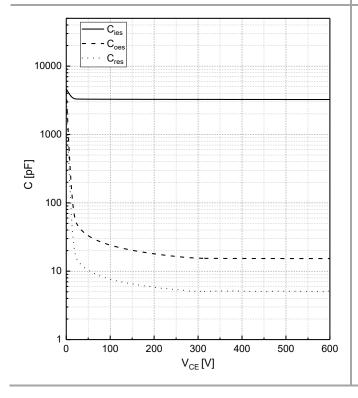
Fig.10 Typical Gate charge V_{GE} =f(Q_G), I_C=30A



15
12
9
6
3
0
0
25
50
75
100
125
Q_G[nC]

Fig.11 Typical capacitance as a function of V_{CE} $C=f(V_{CE}), f=1MHz, V_{GE}=0V$

Fig.12 Collector current as a function of case temperature $I_C=f(T_{vi})$



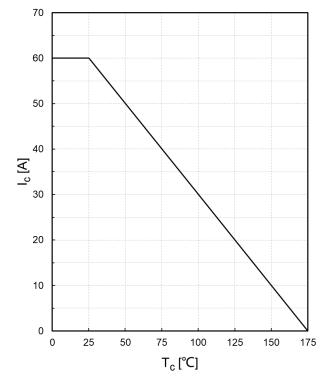
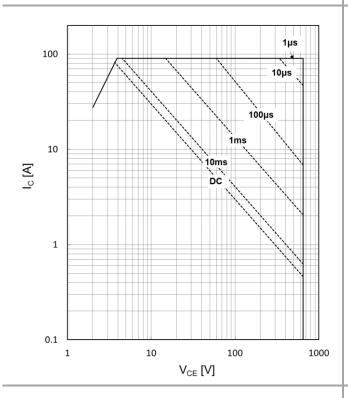




Fig.13 Forward bias safe operating area of IGBT T_c=25°C, T_{vi}≤175°C, V_{GE}=15V

Fig.14 Transient thermal impedance of IGBT $Z_{th(j\text{-}c)}\text{=}f(t_p),\ D\text{=}t_p/T$



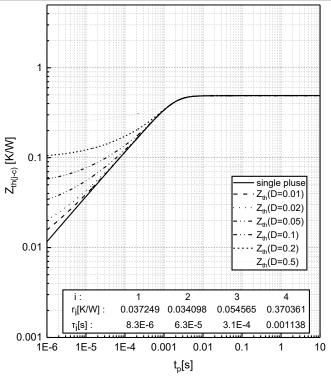
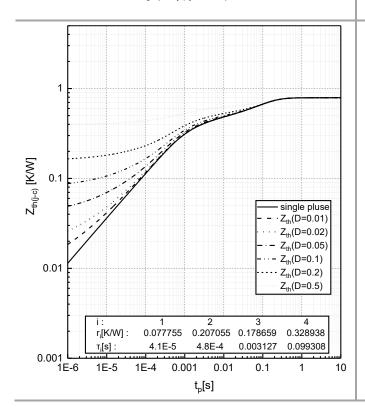


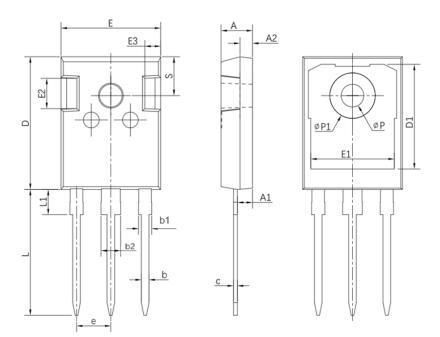
Fig.15 Transient thermal impedance of Diode $Z_{th(j-c)}=f(t_p), D=t_p/T$







5 Package Outlines



SYMBOL	mm				
STIVIDOL	MIN	NOM	MAX		
Α	4.80	5.00	5.20		
A1	2.21	2.41	2.59		
A2	1.85	2.00	2.15		
b	1.11	1.21	1.36		
b1	1.91	2.01	2.25		
b2	2.91	3.01	3.25		
С	0.51	0.61	0.75		
D	20.80	21.00	21.30		
D1	16.25	16.55	16.85		
E	15.50	15.80	16.10		
E1	13.00	13.30	13.60		
E2	4.80	5.00	5.20		
E3	2.30	2.50	2.70		
e	5.44BSC				
L	19.62	19.92	20.22		
L1	-	-	4.30		
ΦР	3.40	3.60	3.80		
ФР1	-	-	7.30		
S	6.15BSC				

Contact Information

No.1001, Shiwan(7) Road, Pudong District, Shanghai, P.R.China.201202 Tel: 86-21-50310888 Fax: 86-21-50757680 Email: market@way-on.com

WAYON website: http://www.way-on.com

For additional information, please contact your local Sales Representative.

WHYDN ® is registered trademarks of Wayon Corporation.





Product Specification Statement

1. The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.

2.The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. WAYON shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and WAYON assumes no responsibility for the application of the product.

3.WAYON strives to provide accurate and up-to-date information to the best of our ability. However, due to technical, human, or other reasons, WAYON cannot guarantee that the information provided in the product specification is entirely accurate and error-free. WAYON shall not be held responsible for any losses or damages resulting from the use or reliance on any information in these product specifications. WAYON reserves the right to revise or update the product specification and the products at any time without prior notice, and the user's continued use of the product specification is considered an acceptance of these revisions and updates. Prior to purchasing and using the product, users should verify the above information with WAYON to ensure that the product specification is the most current, effective, and complete. If users are particularly concerned about product parameters, please consult WAYON in detail or request relevant product test reports. Any data not explicitly mentioned in the product specification shall be subject to separate agreement.

4.Users are advised to pay attention to the parameter limit values specified in the product specification and maintain a certain margin in design or application to ensure that the product does not exceed the parameter limit values defined in the product specification. This precaution should be taken to avoid exceeding one or more of the limit values, which may result in permanent irreversible damage to the product, ultimately affecting the quality and reliability of the system or equipment.

5. The design of the product is intended to meet civilian needs and is not guaranteed for use in harsh environments or precision equipment. It is not recommended for use in systems or equipment such as medical devices, aircraft, nuclear power, and similar systems, where failures in these systems or equipment could reasonably be expected to result in personal injury. WAYON shall assume no responsibility for any consequences resulting from such usage.

6.Users should also comply with relevant laws, regulations, policies, and standards when using the product specification. Users are responsible for the risks and liabilities arising from the use of the product specification and must ensure that it is not used for illegal purposes. Additionally, users should respect the intellectual property rights related to the product specification and refrain from infringing upon any third-party legal rights. WAYON shall assume no responsibility for any disputes or controversies arising from the above-mentioned issues in any form.

